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U.S. **UTILITY** Patent Application

PATENT NUMBER and ISSUE DATE

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APPL NU	1	CLASS	SUBCLASS	GAU	EVANUE -
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**APPLICA	VTS: Kofuii N	Jaovuki: M	lori Masshits		
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TLE: Method	for manufacturing a	semicondu	ictor device		
				U.S	DEPT. OF COMM./PAT.& TM-PTO-436L(Rev. 12-94)

NOTICE OF ALL	OWANCE MAILED		CLA	CLAIMS ALLOWED			
		Assistant Examiner	Total Claims		Print C O.G	laim for	
ISSUE FEE			 	DRAWING			
Amount Due	Date Paid		Sheets Drwg.	Figs.Drw		Print Fig.	
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TER	RMINAL	PREPARED FOR ISSUE	Application	Examine	r		
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